



Features

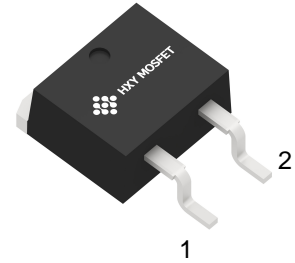
- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

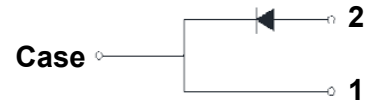
- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives



TO-263N



| Part Number | Package | Qty(PCS) |
|--------------|---------|----------|
| C6D08065G-TR | TO-263N | 800 |

Maximum Ratings ($T_C = 25^\circ\text{C}$ unless otherwise specified)

| Symbol | Parameter | Value | Unit | Test Conditions |
|----------------|--|-------------------|----------------------|--|
| V_{RRM} | Repetitive Peak Reverse Voltage | 650 | V | |
| V_{RSM} | Surge Peak Reverse Voltage | 650 | V | |
| I_F | Continuous Forward Current | 27.5 12.7 8 | A | $T_C=25^\circ\text{C}$ $T_C=135^\circ\text{C}$ $T_C=156^\circ\text{C}$ |
| I_{FRM} | Repetitive Peak Forward Surge Current | 44 | A | $T_C=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave |
| I_{FSM} | Non-Repetitive Peak Forward Surge Current | 88 | A | $T_C=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave |
| P_{tot} | Power Dissipation | 103 45 | W | $T_C=25^\circ\text{C}$ $T_C=110^\circ\text{C}$ |
| T_J, T_{stg} | Operating Junction and Storage Temperature | -55 to +175 | $^\circ\text{C}$ | |
| $\int i^2 dt$ | $i^2 dt$ value | 38.72 | A^2s | $T_C=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave |



Electrical Characteristics

| Symbol | Parameter | Min. | Typ. | Max. | Unit | Test Conditions |
|----------|---------------------------|------|-----------------|-----------|---------------|--|
| V_{DC} | DC Blocking Voltage | 650 | | | V | |
| V_F | Forward Voltage | | 1.38 1.65 | 1.7 2 | V | $I_F = 8\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 8\text{ A}$ $T_J = 175^\circ\text{C}$ |
| I_R | Reverse Current | | 0.2 2 | 50 100 | μA | $V_R = 650\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 650\text{ V}$ $T_J = 175^\circ\text{C}$ |
| Q_C | Total Capacitive Charge | | 28 | | nC | $V_R = 400\text{ V}$ $T_J = 25^\circ\text{C}$ |
| C | Total Capacitance | | 541 55 54 | | pF | $V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ |
| E_C | Capacitance Stored Energy | | 7 | | μJ | $V_R = 400\text{ V}$ |

Thermal Characteristics

| Symbol | Parameter | Typ. | Unit |
|-----------------|--|------|--------------------|
| $R_{\theta JC}$ | Thermal Resistance from Junction to Case | 1.45 | $^\circ\text{C/W}$ |

Typical Performance

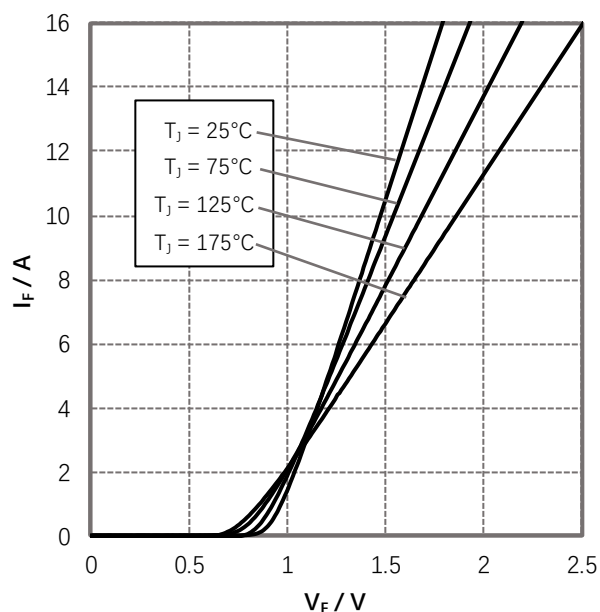


Figure 1. Forward Characteristics

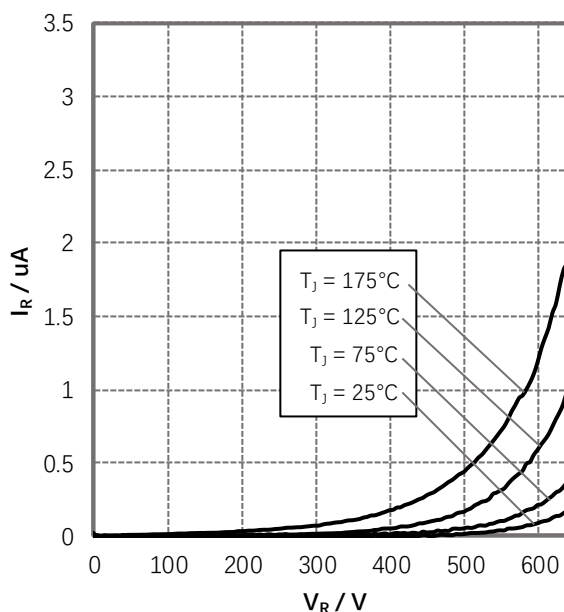


Figure 2. Reverse Characteristics

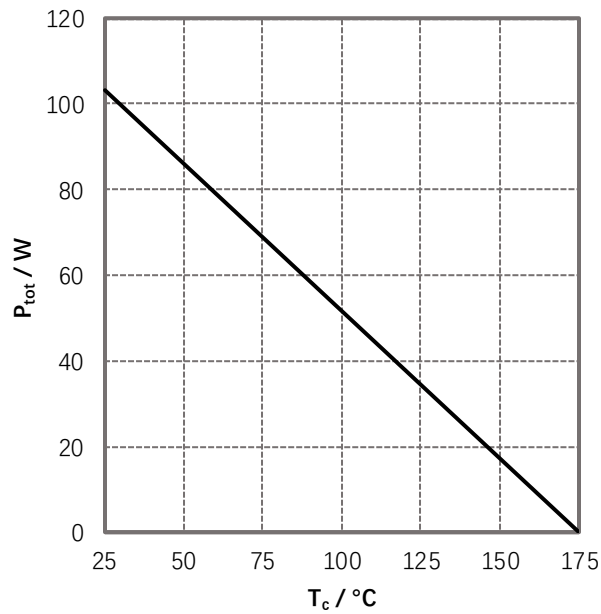


Figure 3. Power Derating

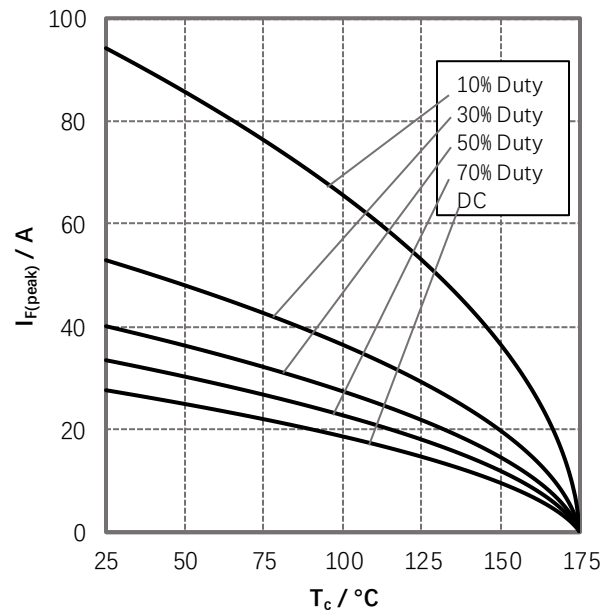


Figure 4. Current Derating

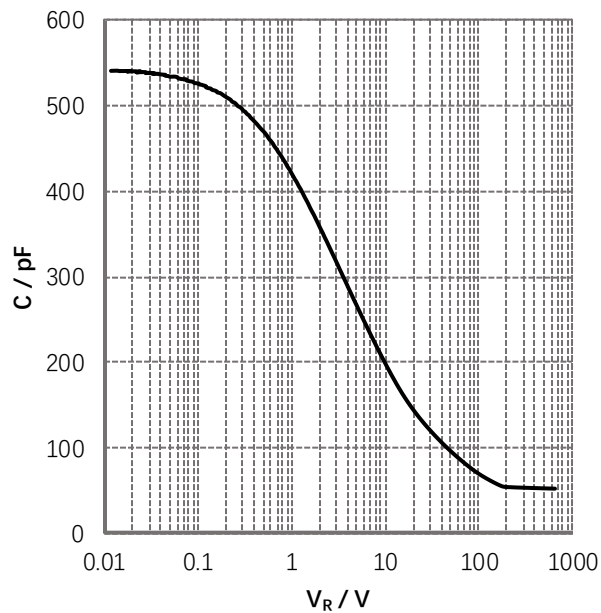


Figure 5. Capacitance vs. Reverse Voltage

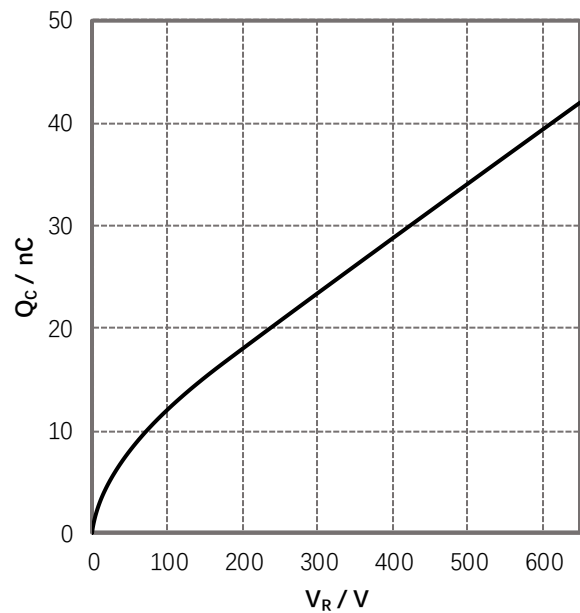


Figure 6. Total Capacitance Charge vs. Reverse Voltage

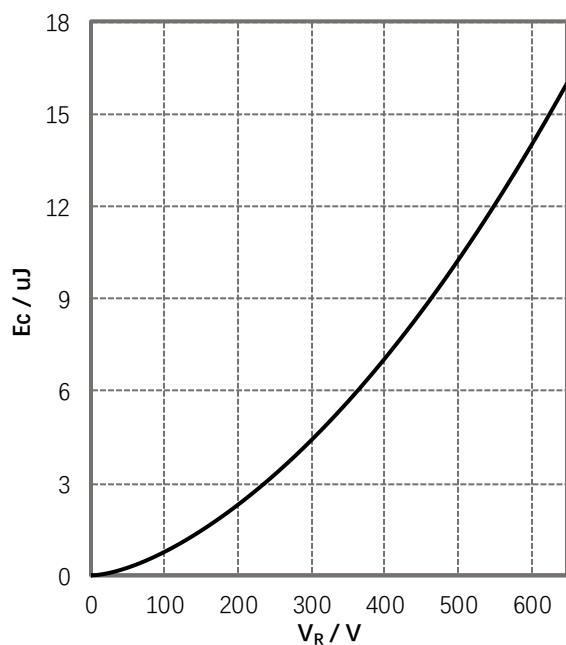


Figure 7. Capacitance Stored Energy

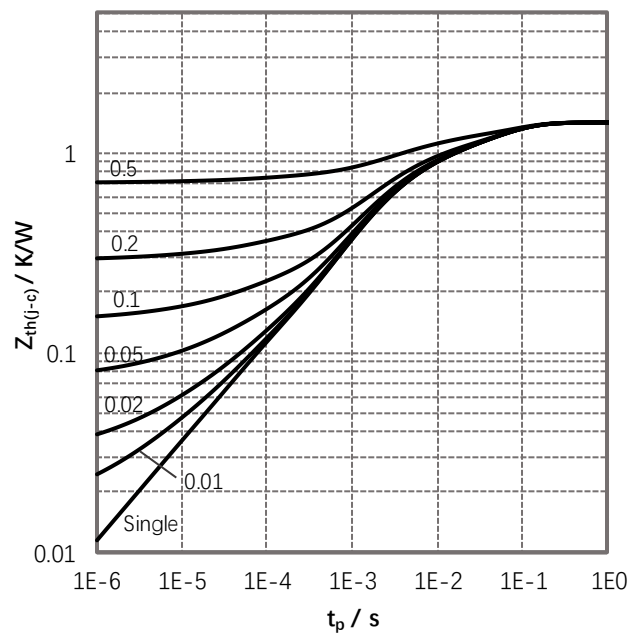
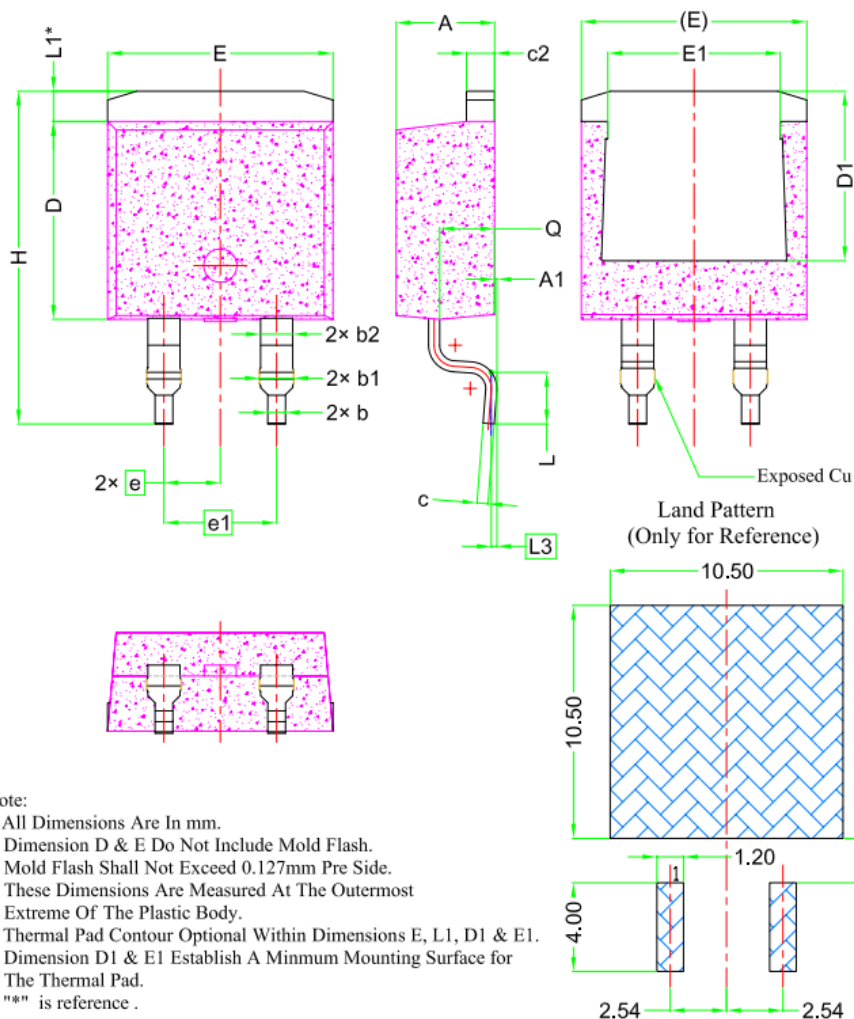


Figure 8. Transient Thermal Impedance



Package Information TO-263N



| SYMBOL | DIMENSIONS | | |
|--------|------------|-------|-------|
| | MIN. | NOM. | MAX. |
| A | 4.24 | 4.44 | 4.64 |
| A1 | 0.00 | 0.10 | 0.25 |
| b | 0.70 | 0.80 | 0.90 |
| b1 | 1.20 | 1.55 | 1.75 |
| b2 | 1.20 | 1.45 | 1.70 |
| c | 0.40 | 0.50 | 0.60 |
| c2 | 1.15 | 1.27 | 1.40 |
| D | 8.82 | 8.92 | 9.02 |
| D1 | 6.86 | 7.65 | — |
| E | 9.96 | 10.16 | 10.36 |
| E1 | 6.89 | 7.77 | 7.89 |
| e | 2.54 BSC | | |
| e1 | 5.08 BSC | | |
| H | 14.61 | 15.00 | 15.88 |
| L | 1.78 | 2.32 | 2.79 |
| L1 | 1.36 REF. | | |
| L3 | 0.25 BSC | | |
| Q | 2.30 | 2.48 | 2.70 |

Note:

1. All Dimensions Are In mm.
2. Dimension D & E Do Not Include Mold Flash.
Mold Flash Shall Not Exceed 0.127mm Pre Side.
These Dimensions Are Measured At The Outermost
Extreme Of The Plastic Body.
3. Thermal Pad Contour Optional Within Dimensions E, L1, D1 & E1.
4. Dimension D1 & E1 Establish A Minmum Mounting Surface for
The Thermal Pad.
5. "REF." is reference .



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